

2.0 Amp Output Current IGBT Gate Drive Optocoupler

Technical Data

HCPL-3120
HCPL-J312
HCNW3120

Features

- **2.0 A Minimum Peak Output Current**
- **15 kV/μs Minimum Common Mode Rejection (CMR) at $V_{CM} = 1500$ V**
- **0.5 V Maximum Low Level Output Voltage (V_{OL})**
Eliminates Need for Negative Gate Drive
- **$I_{CC} = 5$ mA Maximum Supply Current**
- **Under Voltage Lock-Out Protection (UVLO) with Hysteresis**
- **Wide Operating V_{CC} Range: 15 to 30 Volts**
- **500 ns Maximum Switching Speeds**
- **Industrial Temperature Range: -40°C to 100°C**
- **Safety Approval**
UL Recognized
2500 Vrms for 1 min. for HCPL-3120
3750 Vrms for 1 min. for HCPL-J312
5000 Vrms for 1 min. for HCNW3120

CSA Approval

VDE 0884 Approved

$V_{IORM} = 630$ Vpeak for HCPL-3120 (Option 060)

$V_{IORM} = 891$ Vpeak for HCPL-J312

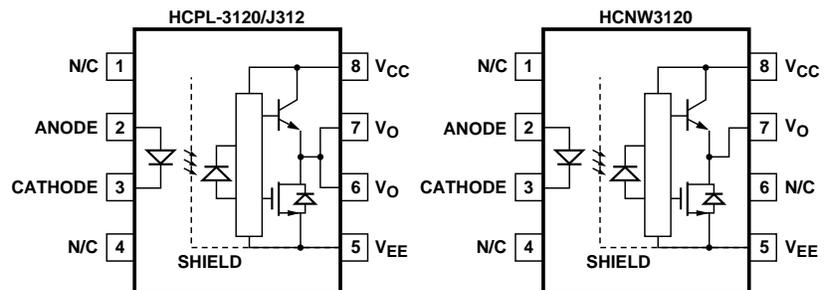
$V_{IORM} = 1414$ Vpeak for HCNW3120

BSI Certified (HCNW3120 only) (Pending)

Applications

- **IGBT/MOSFET Gate Drive**
- **AC/Brushless DC Motor Drives**
- **Industrial Inverters**
- **Switch Mode Power Supplies**

Functional Diagram



TRUTH TABLE

| LED | $V_{CC} - V_{EE}$ "POSITIVE GOING" (i.e., TURN-ON) | $V_{CC} - V_{EE}$ "NEGATIVE GOING" (i.e., TURN-OFF) | V_O |
|-----|--|---|------------|
| OFF | 0 - 30 V | 0 - 30 V | LOW |
| ON | 0 - 11 V | 0 - 9.5 V | LOW |
| ON | 11 - 13.5 V | 9.5 - 12 V | TRANSITION |
| ON | 13.5 - 30 V | 12 - 30 V | HIGH |

A 0.1 μF bypass capacitor must be connected between pins 5 and 8.

CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.

Description

The HCPL-3120 contains a GaAsP LED while the HCPL-J312 and the HCNW3120 contain an AlGaAs LED. The LED is optically coupled to an integrated circuit with a power output stage. These optocouplers are ideally suited for driving power IGBTs and MOSFETs used in motor control inverter applications. The high

operating voltage range of the output stage provides the drive voltages required by gate controlled devices. The voltage and current supplied by these optocouplers make them ideally suited for directly driving IGBTs with ratings up to 1200 V/100 A. For IGBTs with higher ratings, the HCPL-3120 series can be used to drive a discrete power

stage which drives the IGBT gate. The HCNW3120 has the highest insulation voltage of $V_{IORM} = 1414 V_{peak}$ in the VDE0884. The HCPL-J312 has an insulation voltage of $V_{IORM} = 891 V_{peak}$ and the $V_{IORM} = 630 V_{peak}$ is also available with the HCPL-3120 (Option 060).

Selection Guide

| Part Number | HCPL-3120 | HCPL-J312 | HCNW3120 | HCPL-3150* |
|-------------------------------|---|---------------------------|----------------------------|---|
| Output Peak Current (I_O) | 2.0 A | 2.0 A | 2.0 A | 0.5 A |
| VDE0884 Approval | $V_{IORM} = 630 V_{peak}$ (Option 060) | $V_{IORM} = 891 V_{peak}$ | $V_{IORM} = 1414 V_{peak}$ | $V_{IORM} = 630 V_{peak}$ (Option 060) |

*The HCPL-3150 Data sheet available. Contact Agilent sales representative or authorized distributor.

Ordering Information

Specify Part Number followed by Option Number (if desired)

Example:

HCPL-3120#XXX

- 060 = VDE0884, $V_{IORM} = 630 V_{peak}$ (HCPL-3120 only)
- 300 = Gull Wing Surface Mount Option
- 500 = Tape and Reel Packaging Option

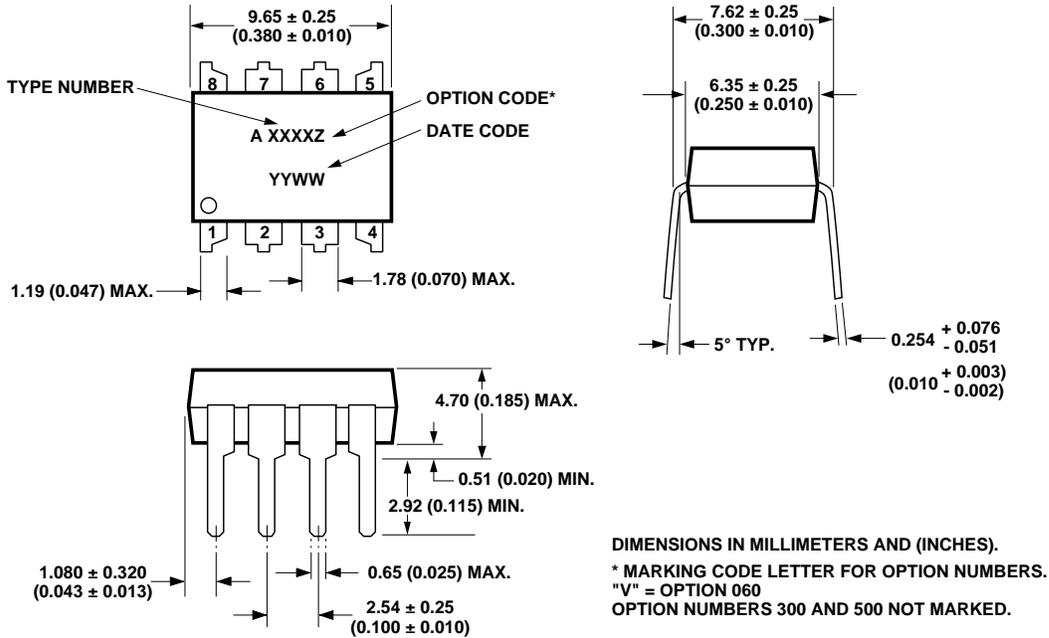
Option 500 contains 1000 units (HCPL-3120/J312), 750 units (HCNW3120) per reel.

Other options contain 50 units (HCPL-3120/J312), 42 units (HCNW312) per tube.

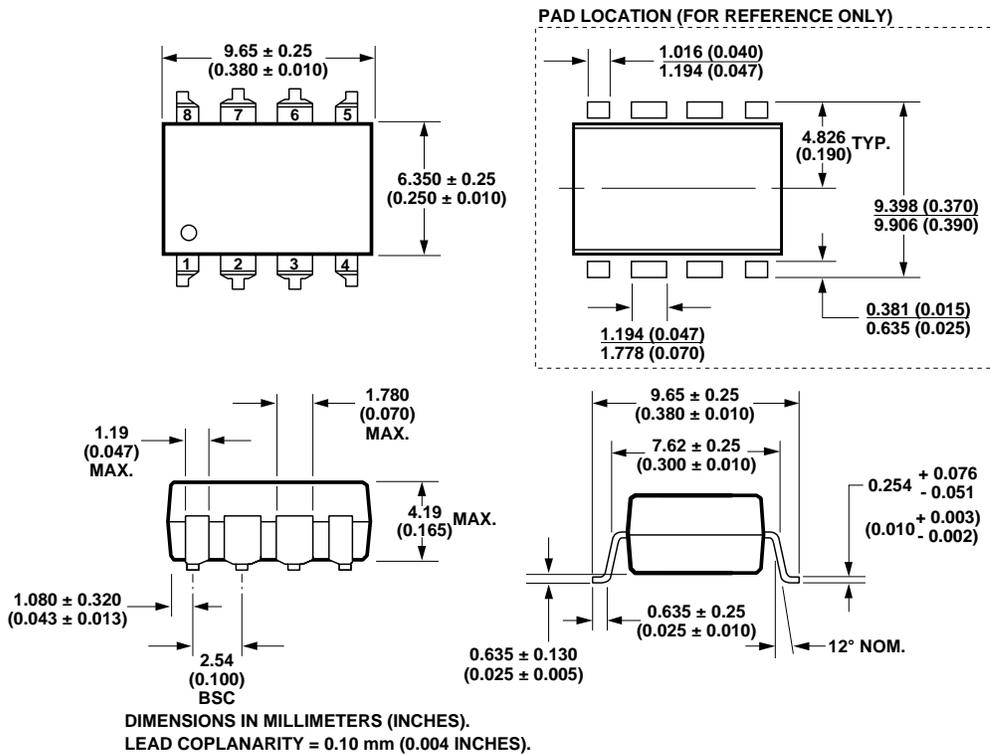
Option data sheets available. Contact Agilent sales representative or authorized distributor.

Package Outline Drawings

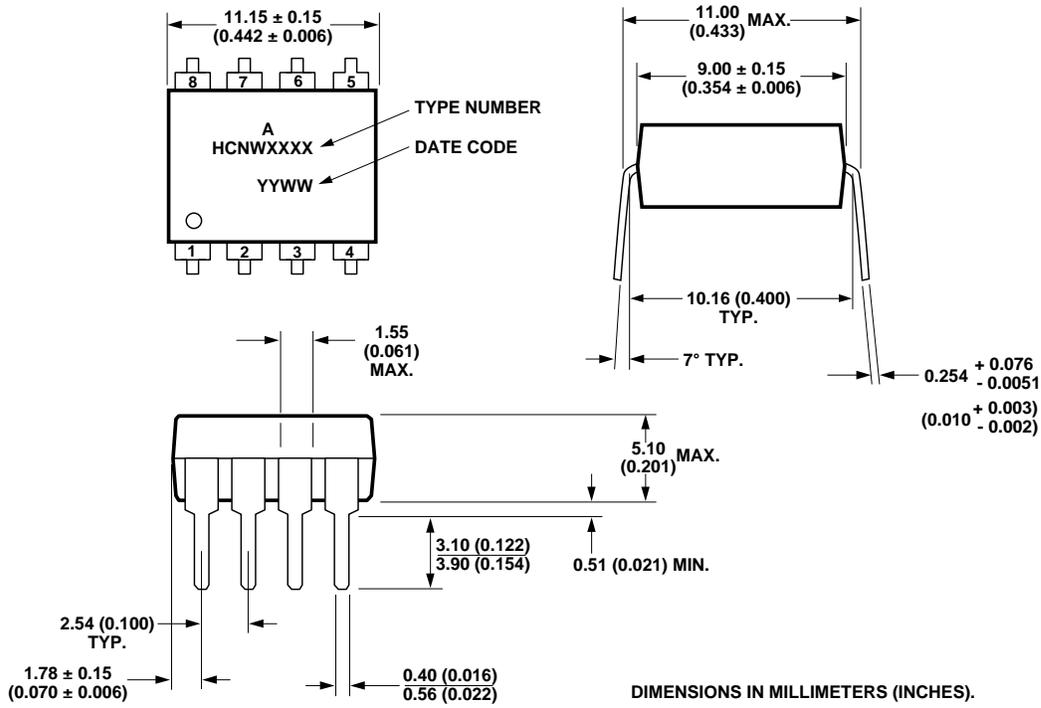
HCPL-3120 and HCPL-J312 Outline Drawing (Standard DIP Package)



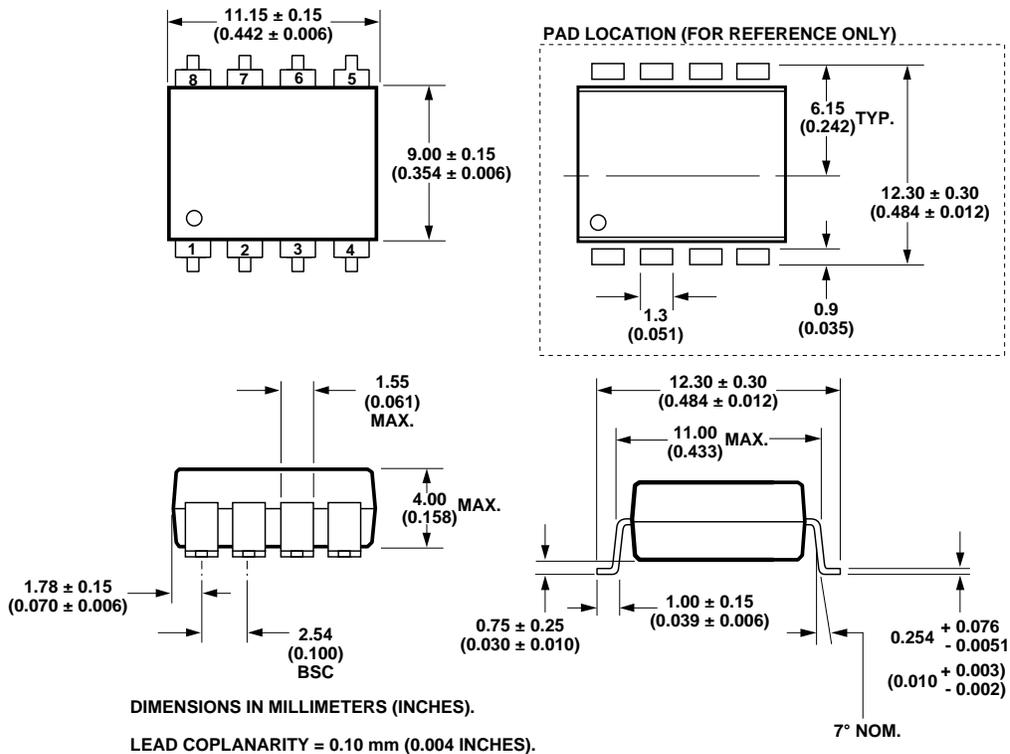
HCPL-3120 and HCPL-J312 Gull Wing Surface Mount Option 300 Outline Drawing



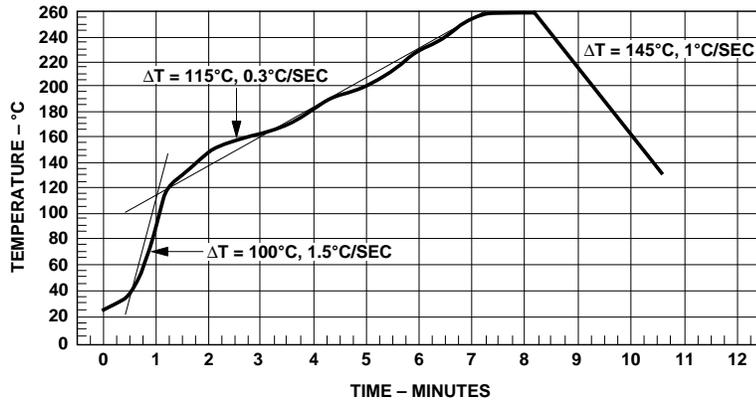
HCNW3120 Outline Drawing (8-Pin Wide Body Package)



HCNW3120 Gull Wing Surface Mount Option 300 Outline Drawing



Reflow Temperature Profile



MAXIMUM SOLDER REFLOW THERMAL PROFILE

(NOTE: USE OF NON-CHLORINE ACTIVATED FLUXES IS RECOMMENDED.)

Regulatory Information

| Agency/Standard | HCPL-3120 | HCPL-J312 | HCNW3120 |
|---|-----------------|-----------|----------|
| Underwriters Laboratory (UL) Recognized under UL 1577, Component Recognition Program, Category, File E55361 | ✓ | ✓ | ✓ |
| Canadian Standards Association (CSA) File CA88324, per Component Acceptance Notice #5 | ✓ | ✓ | ✓ |
| Verband Deutscher Elektrotechniker (VDE) DIN VDE 0884 (June 1992) | ✓ Option 060 | ✓ | ✓ |
| British Standards Institute (BSI) Certification According to BS EN60065: 1994 (BS415:1994), BS EN60950: 1992 (BS7002:1992) | | | Pending |

Insulation and Safety Related Specifications

| Parameter | Symbol | Value | | | Units | Conditions |
|---|--------|-----------|-----------|----------|-------|---|
| | | HCPL-3120 | HCPL-J312 | HCNW3120 | | |
| Minimum External Air Gap (Clearance) | L(101) | 7.1 | 7.4 | 9.6 | mm | Measured from input terminals to output terminals, shortest distance through air. |
| Minimum External Tracking (Creepage) | L(102) | 7.4 | 8.0 | 10.0 | mm | Measured from input terminals to output terminals, shortest distance path along body. |
| Minimum Internal Plastic Gap (Internal Clearance) | | 0.08 | 0.5 | 1.0 | mm | Insulation thickness between emitter and detector; also known as distance through insulation. |
| Tracking Resistance (Comparative Tracking Index) | CTI | >175 | >175 | >200 | Volts | DIN IEC 112/VDE 0303 Part 1 |
| Isolation Group | | IIIa | IIIa | IIIa | | Material Group (DIN VDE 0110, 1/89, Table 1) |

All Agilent data sheets report the creepage and clearance inherent to the optocoupler component itself. These dimensions are needed as a starting point for the equipment designer when determining the circuit insulation requirements. However, once mounted on a printed circuit

board, minimum creepage and clearance requirements must be met as specified for individual equipment standards. For creepage, the shortest distance path along the surface of a printed circuit board between the solder fillets of the input and output leads must be considered. There

are recommended techniques such as grooves and ribs which may be used on a printed circuit board to achieve desired creepage and clearances. Creepage and clearance distances will also change depending on factors such as pollution degree and insulation level.

VDE0884 Insulation Related Characteristics

| Description | Symbol | HCPL-3120 Option 060 | HCPL-J312 | HCNW3120 | Unit |
|--|----------------|-------------------------|--------------------------------|---------------------------------------|-------------|
| Installation classification per DIN VDE 0110/1.89, Table 1 for rated mains voltage ≤ 150 V rms for rated mains voltage ≤ 300 V rms for rated mains voltage ≤ 450 V rms for rated mains voltage ≤ 600 V rms for rated mains voltage ≤ 1000 V rms | | I-IV I-IV I-III | I-IV I-IV I-III I-III | I-IV I-IV I-IV I-IV I-III | |
| Climatic Classification | | 55/100/21 | 55/100/21 | 55/100/21 | |
| Pollution Degree (DIN VDE 0110/1.89) | | 2 | 2 | 2 | |
| Maximum Working Insulation Voltage | V_{IORM} | 630 | 891 | 1414 | V_{peak} |
| Input to Output Test Voltage, Method b* $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test, $t_m = 1$ sec, Partial Discharge $< 5pC$ | V_{PR} | 1181 | 1670 | 2652 | V_{peak} |
| Input to Output Test Voltage, Method a* $V_{IORM} \times 1.5 = V_{PR}$, Type and Sample Test, $t_m = 60$ sec, Partial Discharge $< 5pC$ | V_{PR} | 945 | 1336 | 2121 | V_{peak} |
| Highest Allowable Overvoltage* (Transient Overvoltage, $t_{ini} = 10$ sec) | V_{IOTM} | 6000 | 6000 | 8000 | V_{peak} |
| Safety Limiting Values – maximum values allowed in the event of a failure, also see Figure 37. | | | | | |
| Case Temperature | T_S | 175 | 175 | 150 | $^{\circ}C$ |
| Input Current | $I_{S INPUT}$ | 230 | 400 | 400 | mA |
| Output Power | $P_{S OUTPUT}$ | 600 | 600 | 700 | mW |
| Insulation Resistance at $T_S, V_{IO} = 500$ V | R_S | $\geq 10^9$ | $\geq 10^9$ | $\geq 10^9$ | Ω |

*Refer to the VDE0884 section (page 1-6/8) of the Isolation Control Component Designer's Catalog for a detailed description of Method a/b partial discharge test profiles.

Note: These optocouplers are suitable for “safe electrical isolation” only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits. Surface mount classification is Class A in accordance with CECC 00802.

Absolute Maximum Ratings

| Parameter | Symbol | Min. | Max. | Units | Note |
|---|--------------------------------------|---|----------|-------|------|
| Storage Temperature | T_S | -55 | 125 | °C | |
| Operating Temperature | T_A | -40 | 100 | °C | |
| Average Input Current | $I_{F(AVG)}$ | | 25 | mA | 1 |
| Peak Transient Input Current ($< 1 \mu s$ pulse width, 300 pps) | $I_{F(TRAN)}$ | | 1.0 | A | |
| Reverse Input Voltage | HCPL-3120 | V_R | 5 | Volts | |
| | HCPL-J312 | | 3 | | |
| | HCNW3120 | | | | |
| “High” Peak Output Current | $I_{OH(PEAK)}$ | | 2.5 | A | 2 |
| “Low” Peak Output Current | $I_{OL(PEAK)}$ | | 2.5 | A | 2 |
| Supply Voltage | $(V_{CC} - V_{EE})$ | 0 | 35 | Volts | |
| Input Current (Rise/Fall Time) | $t_{r(IN)} / t_{f(IN)}$ | | 500 | ns | |
| Output Voltage | $V_{O(PEAK)}$ | 0 | V_{CC} | Volts | |
| Output Power Dissipation | P_O | | 250 | mW | 3 |
| Total Power Dissipation | P_T | | 295 | mW | 4 |
| Lead Solder Temperature | HCPL-3120 | 260°C for 10 sec., 1.6 mm below seating plane | | | |
| | HCPL-J312 | | | | |
| | HCNW3120 | 260°C for 10 sec., up to seating plane | | | |
| Solder Reflow Temperature Profile | See Package Outline Drawings section | | | | |

Recommended Operating Conditions

| Parameter | Symbol | Min. | Max. | Units |
|-----------------------|---------------------|-------------|------|-------|
| Power Supply Voltage | $(V_{CC} - V_{EE})$ | 15 | 30 | Volts |
| Input Current (ON) | HCPL-3120 | $I_{F(ON)}$ | 7 | mA |
| | HCPL-J312 | | | |
| | HCNW3120 | | 10 | |
| Input Voltage (OFF) | $V_{F(OFF)}$ | -3.0 | 0.8 | V |
| Operating Temperature | T_A | -40 | 100 | °C |

Electrical Specifications (DC)

Over recommended operating conditions ($T_A = -40$ to 100°C , $I_{F(\text{ON})} = 7$ to 16 mA, $V_{F(\text{OFF})} = -3.0$ to 0.8 V, $V_{CC} = 15$ to 30 V, $V_{EE} = \text{Ground}$) unless otherwise specified.

| Parameter | Symbol | Device | Min. | Typ.* | Max. | Units | Test Conditions | Fig. | Note |
|--|---------------------------|-----------|----------------|----------------|------|----------------------|--|--------------|------|
| High Level Output Current | I_{OH} | | 0.5 | 1.5 | | A | $V_O = (V_{CC} - 4 \text{ V})$ | 2, 3, | 5 |
| | | | 2.0 | | | A | $V_O = (V_{CC} - 15 \text{ V})$ | 17 | 2 |
| Low Level Output Current | I_{OL} | | 0.5 | 2.0 | | A | $V_O = (V_{EE} + 2.5 \text{ V})$ | 5, 6, | 5 |
| | | | 2.0 | | | A | $V_O = (V_{EE} + 15 \text{ V})$ | 18 | 2 |
| High Level Output Voltage | V_{OH} | | $(V_{CC} - 4)$ | $(V_{CC} - 3)$ | | V | $I_O = -100 \text{ mA}$ | 1, 3, 19 | 6, 7 |
| Low Level Output Voltage | V_{OL} | | | 0.1 | 0.5 | V | $I_O = 100 \text{ mA}$ | 4, 6, 20 | |
| High Level Supply Current | I_{CCH} | | | 2.5 | 5.0 | mA | Output Open, $I_F = 7$ to 16 mA | 7, 8 | |
| Low Level Supply Current | I_{CCL} | | | 2.5 | 5.0 | mA | Output Open, $V_F = -3.0$ to $+0.8 \text{ V}$ | | |
| Threshold Input Current Low to High | I_{FLH} | HCPL-3120 | | 2.3 | 5.0 | mA | $I_O = 0 \text{ mA}$, $V_O > 5 \text{ V}$ | 9, 15, 21 | |
| | | HCPL-J312 | | 1.0 | | | | | |
| | | HCNW3120 | | 2.3 | 8.0 | | | | |
| Threshold Input Voltage High to Low | V_{FHL} | | 0.8 | | | V | | | |
| Input Forward Voltage | V_F | HCPL-3120 | 1.2 | 1.5 | 1.8 | V | $I_F = 10 \text{ mA}$ | 16 | |
| | | HCPL-J312 | | 1.6 | 1.95 | | | | |
| | | HCNW3120 | | | | | | | |
| Temperature Coefficient of Forward Voltage | $\Delta V_F / \Delta T_A$ | HCPL-3120 | | -1.6 | | mV/ $^\circ\text{C}$ | $I_F = 10 \text{ mA}$ | | |
| | | HCPL-J312 | | -1.3 | | | | | |
| | | HCNW3120 | | | | | | | |
| Input Reverse Breakdown Voltage | BV_R | HCPL-3120 | 5 | | | V | $I_R = 10 \mu\text{A}$ | | |
| | | HCPL-J312 | 3 | | | | $I_R = 100 \mu\text{A}$ | | |
| | | HCNW3120 | | | | | | | |
| Input Capacitance | C_{IN} | HCPL-3120 | | 60 | | pF | $f = 1 \text{ MHz}$, $V_F = 0 \text{ V}$ | | |
| | | HCPL-J312 | | 70 | | | | | |
| | | HCNW3120 | | | | | | | |
| UVLO Threshold | V_{UVLO+} | | 11.0 | 12.3 | 13.5 | V | $V_O > 5 \text{ V}$, $I_F = 10 \text{ mA}$ | 22, 34 | |
| | V_{UVLO-} | | 9.5 | 10.7 | 12.0 | | | | |
| UVLO Hysteresis | $UVLO_{HYS}$ | | | 1.6 | | | | | |

*All typical values at $T_A = 25^\circ\text{C}$ and $V_{CC} - V_{EE} = 30 \text{ V}$, unless otherwise noted.

Switching Specifications (AC)

Over recommended operating conditions ($T_A = -40$ to 100°C , $I_{F(\text{ON})} = 7$ to 16 mA, $V_{F(\text{OFF})} = -3.0$ to 0.8 V, $V_{CC} = 15$ to 30 V, $V_{EE} = \text{Ground}$) unless otherwise specified.

| Parameter | Symbol | Min. | Typ.* | Max. | Units | Test Conditions | Fig. | Note | |
|---|--|-------|-------|------|-------------------|--|------------------------------|--------|----|
| Propagation Delay Time to High Output Level | t_{PLH} | 0.10 | 0.30 | 0.50 | μs | Rg = 10 Ω , Cg = 10 nF, f = 10 kHz, Duty Cycle = 50% | 10, 11, 12, 13, 14, 23 | 16 | |
| Propagation Delay Time to Low Output Level | t_{PHL} | 0.10 | 0.30 | 0.50 | μs | | | | |
| Pulse Width Distortion | PWD | | | 0.3 | μs | | | | |
| Propagation Delay Difference Between Any Two Parts | PDD ($t_{\text{PHL}} - t_{\text{PLH}}$) | -0.35 | | 0.35 | μs | | | 35, 36 | 12 |
| Rise Time | t_r | | 0.1 | | μs | | | 23 | |
| Fall Time | t_f | | 0.1 | | μs | | | | |
| UVLO Turn On Delay | $t_{\text{UVLO ON}}$ | | 0.8 | | μs | | $V_O > 5$ V, $I_F = 10$ mA | 22 | |
| UVLO Turn Off Delay | $t_{\text{UVLO OFF}}$ | | 0.6 | | μs | $V_O < 5$ V, $I_F = 10$ mA | | | |
| Output High Level Common Mode Transient Immunity | $ \text{CM}_H $ | 15 | 30 | | kV/ μs | $T_A = 25^\circ\text{C}$, $I_F = 10$ to 16 mA, $V_{\text{CM}} = 1500$ V, $V_{CC} = 30$ V | 24 | 13, 14 | |
| Output Low Level Common Mode Transient Immunity | $ \text{CM}_L $ | 15 | 30 | | kV/ μs | $T_A = 25^\circ\text{C}$, $V_{\text{CM}} = 1500$ V, $V_F = 0$ V, $V_{CC} = 30$ V | | 13, 15 | |

*All typical values at $T_A = 25^\circ\text{C}$ and $V_{CC} - V_{EE} = 30$ V, unless otherwise noted.

Package Characteristics

Over recommended temperature ($T_A = -40$ to 100°C) unless otherwise specified.

| Parameter | Symbol | Device | Min. | Typ. | Max. | Units | Test Conditions | Fig. | Note | |
|--|----------------------|-----------|-----------|-----------|------|--------------------|--|------|--------|---------------------------|
| Input-Output Momentary Withstand Voltage** | V_{ISO} | HCPL-3120 | 2500 | | | V_{RMS} | RH < 50%, t = 1 min., $T_A = 25^\circ\text{C}$ | | 8, 11 | |
| | | HCPL-J312 | 3750 | | | | | | 9, 11 | |
| | | HCNW3120 | 5000 | | | | | | 10, 11 | |
| Resistance (Input-Output) | $R_{\text{I-O}}$ | HCPL-3120 | | 10^{12} | | Ω | $V_{\text{I-O}} = 500 V_{\text{DC}}$ | | 11 | |
| | | HCPL-J312 | | | | | | | | |
| | | HCNW3120 | 10^{12} | 10^{13} | | | | | | $T_A = 25^\circ\text{C}$ |
| | | | 10^{11} | | | | | | | $T_A = 100^\circ\text{C}$ |
| Capacitance (Input-Output) | $C_{\text{I-O}}$ | HCPL-3120 | | 0.6 | | pF | f = 1 MHz | | | |
| | | HCPL-J312 | | 0.8 | | | | | | |
| | | HCNW3120 | | 0.5 | 0.6 | | | | | |
| LED-to-Case Thermal Resistance | θ_{LC} | | | 467 | | $^\circ\text{C/W}$ | Thermocouple located at center underside of package | 28 | | |
| LED-to-Detector Thermal Resistance | θ_{LD} | | | 442 | | $^\circ\text{C/W}$ | | | | |
| Detector-to-Case Thermal Resistance | θ_{DC} | | | 126 | | $^\circ\text{C/W}$ | | | | |

*All typicals at $T_A = 25^\circ\text{C}$.

**The Input-Output Momentary Withstand Voltage is a dielectric voltage rating that should not be interpreted as an input-output continuous voltage rating. For the continuous voltage rating refer to your equipment level safety specification or Agilent Application Note 1074 entitled "Optocoupler Input-Output Endurance Voltage."

Notes:

- Derate linearly above 70°C free-air temperature at a rate of $0.3 \text{ mA}/^\circ\text{C}$.
- Maximum pulse width = $10 \mu\text{s}$, maximum duty cycle = 0.2% . This value is intended to allow for component tolerances for designs with I_{O} peak minimum = 2.0 A . See Applications section for additional details on limiting I_{OH} peak.
- Derate linearly above 70°C free-air temperature at a rate of $4.8 \text{ mW}/^\circ\text{C}$.
- Derate linearly above 70°C free-air temperature at a rate of $5.4 \text{ mW}/^\circ\text{C}$. The maximum LED junction temperature should not exceed 125°C .
- Maximum pulse width = $50 \mu\text{s}$, maximum duty cycle = 0.5% .
- In this test V_{OH} is measured with a dc load current. When driving capacitive loads V_{OH} will approach V_{CC} as I_{OH} approaches zero amps.
- Maximum pulse width = 1 ms , maximum duty cycle = 20% .
- In accordance with UL1577, each optocoupler is proof tested by applying an insulation test voltage $\geq 3000 \text{ Vrms}$ for 1 second (leakage detection current limit, $I_{\text{I-O}} \leq 5 \mu\text{A}$).
- In accordance with UL1577, each optocoupler is proof tested by applying an insulation test voltage $\geq 4500 \text{ Vrms}$ for 1 second (leakage detection current limit, $I_{\text{I-O}} \leq 5 \mu\text{A}$).
- In accordance with UL1577, each optocoupler is proof tested by applying an insulation test voltage $\geq 6000 \text{ Vrms}$ for 1 second (leakage detection current limit, $I_{\text{I-O}} \leq 5 \mu\text{A}$).
- Device considered a two-terminal device: pins 1, 2, 3, and 4 shorted together and pins 5, 6, 7, and 8 shorted together.
- The difference between t_{PHL} and t_{PLH} between any two HCPL-3120 parts under the same test condition.
- Pins 1 and 4 need to be connected to LED common.
- Common mode transient immunity in the high state is the maximum tolerable dV_{CM}/dt of the common mode pulse, V_{CM} , to assure that the output will remain in the high state (i.e., $V_{\text{O}} > 15.0 \text{ V}$).
- Common mode transient immunity in a low state is the maximum tolerable dV_{CM}/dt of the common mode pulse, V_{CM} , to assure that the output will remain in a low state (i.e., $V_{\text{O}} < 1.0 \text{ V}$).
- This load condition approximates the gate load of a $1200 \text{ V}/75\text{A}$ IGBT.
- Pulse Width Distortion (PWD) is defined as $|t_{\text{PHL}} - t_{\text{PLH}}|$ for any given device.

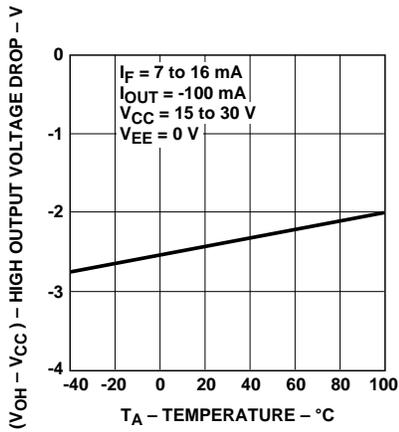


Figure 1. V_{OH} vs. Temperature.

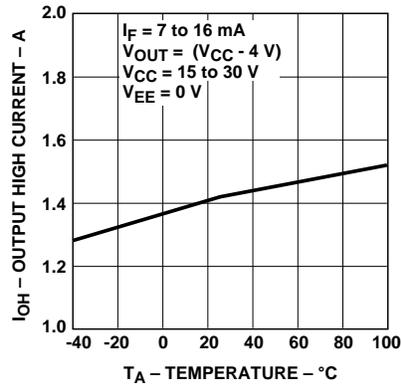


Figure 2. I_{OH} vs. Temperature.

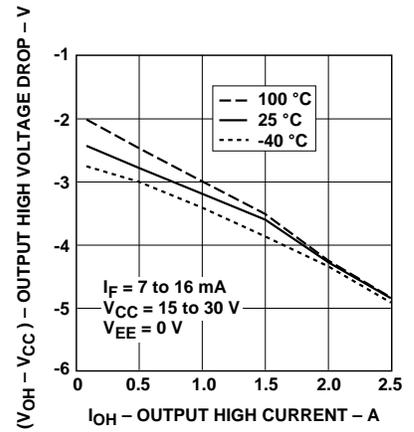


Figure 3. V_{OH} vs. I_{OH} .

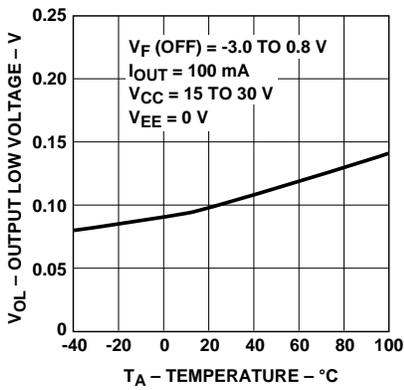


Figure 4. V_{OL} vs. Temperature.

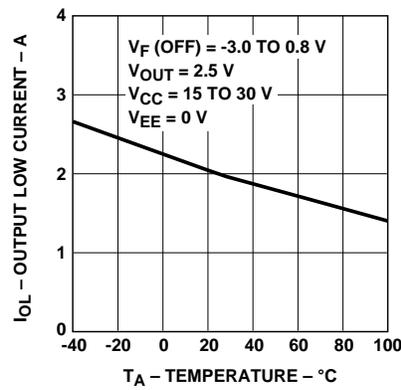


Figure 5. I_{OL} vs. Temperature.

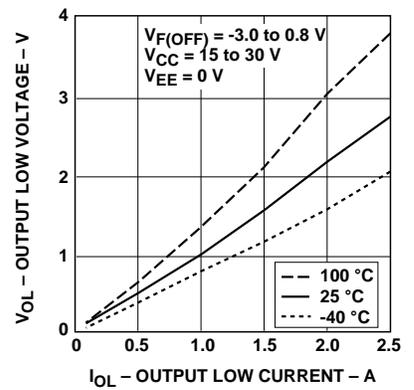


Figure 6. V_{OL} vs. I_{OL} .

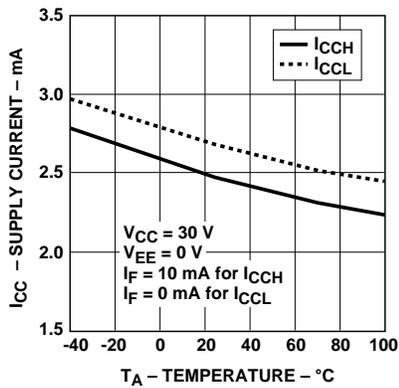


Figure 7. I_{CC} vs. Temperature.

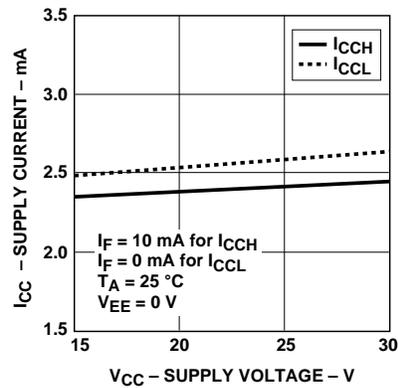


Figure 8. I_{CC} vs. V_{CC} .

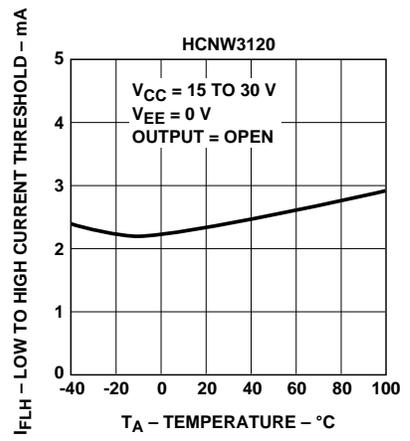
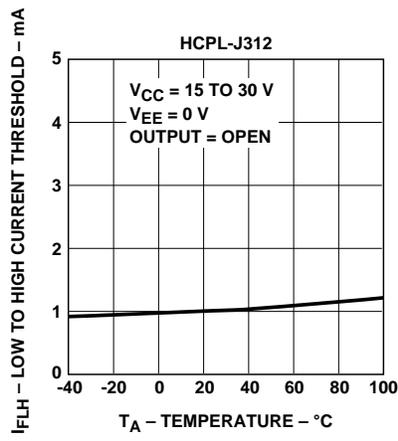
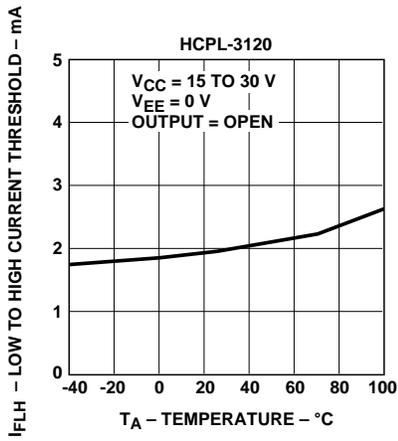


Figure 9. I_{FLH} vs. Temperature.

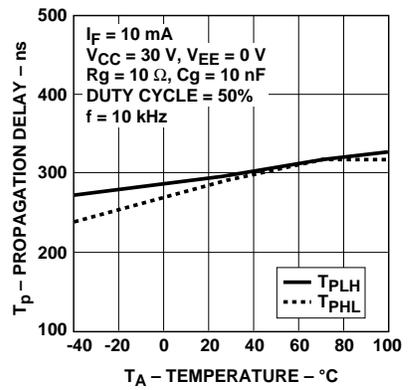
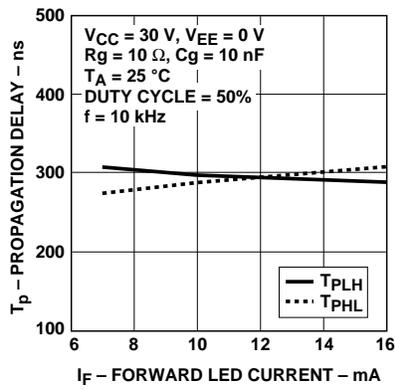
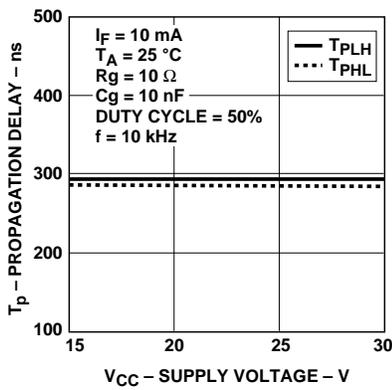


Figure 10. Propagation Delay vs. V_{CC} .

Figure 11. Propagation Delay vs. I_F .

Figure 12. Propagation Delay vs. Temperature.

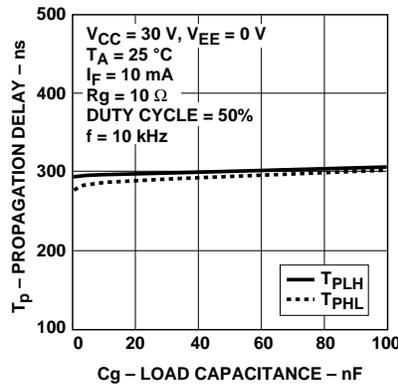
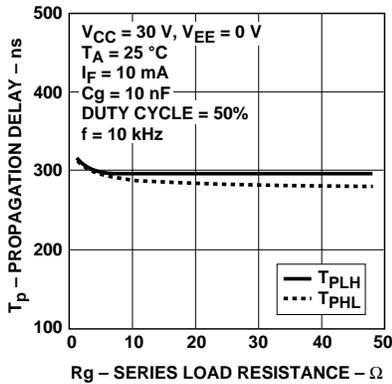


Figure 13. Propagation Delay vs. R_g .

Figure 14. Propagation Delay vs. C_g .

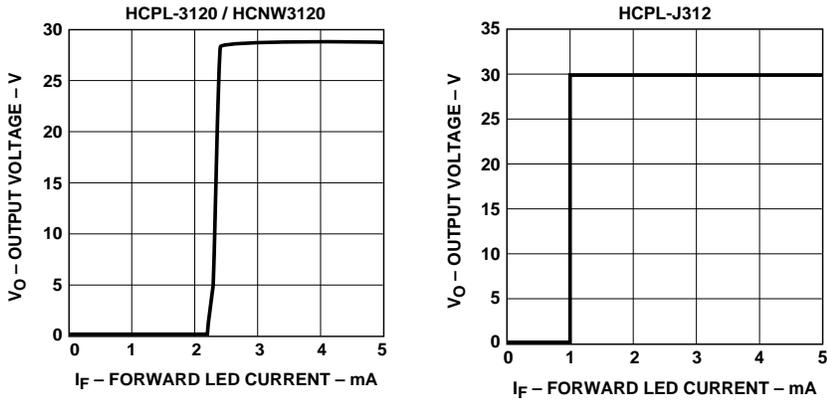


Figure 15. Transfer Characteristics.

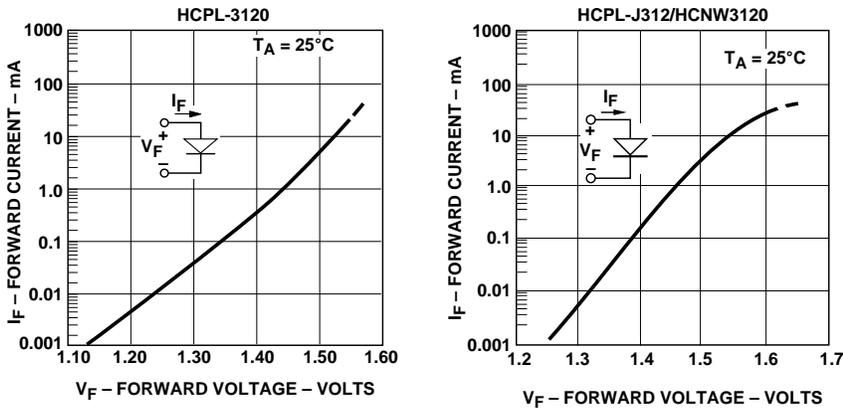


Figure 16. Input Current vs. Forward Voltage.

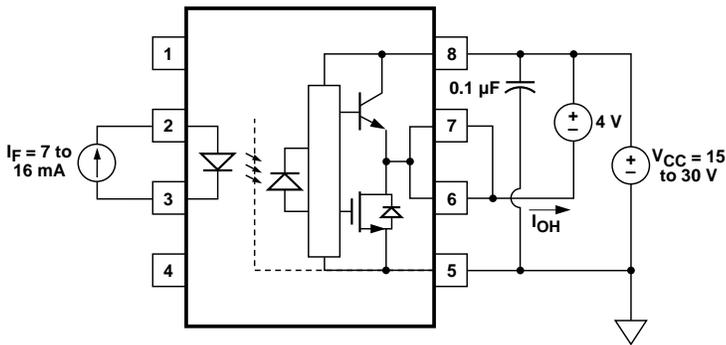


Figure 17. I_{OH} Test Circuit.

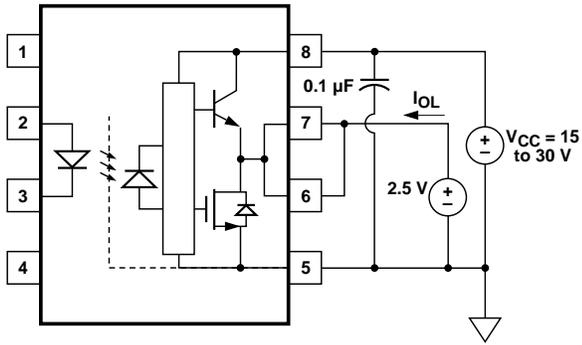


Figure 18. I_{OL} Test Circuit.

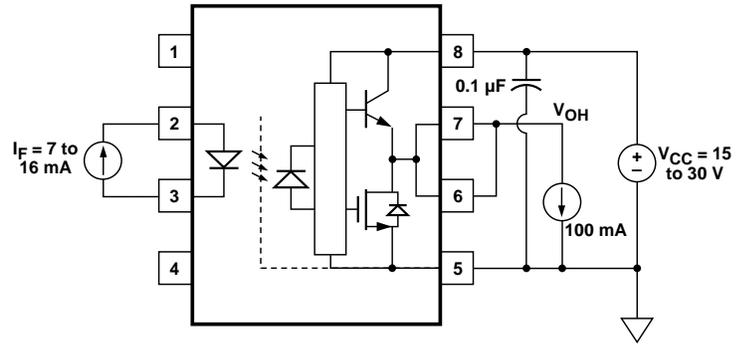


Figure 19. V_{OH} Test Circuit.

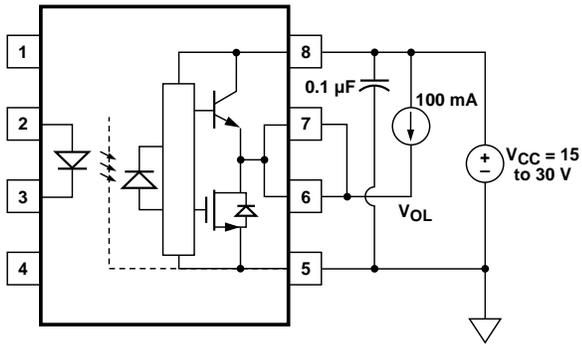


Figure 20. V_{OL} Test Circuit.

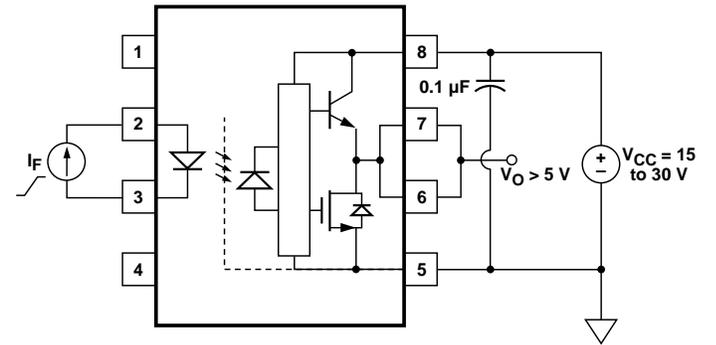


Figure 21. I_{FLH} Test Circuit.

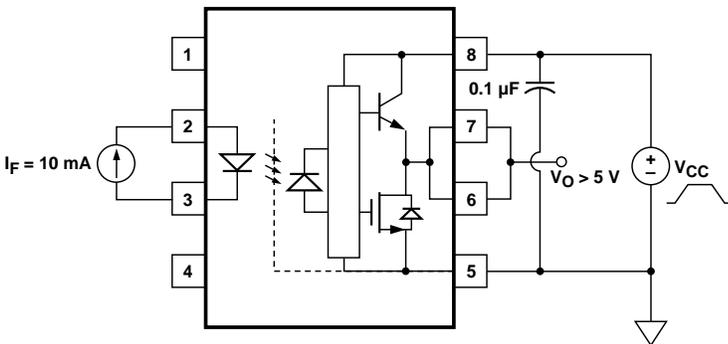


Figure 22. UVLO Test Circuit.

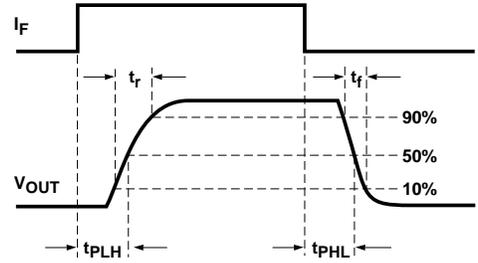
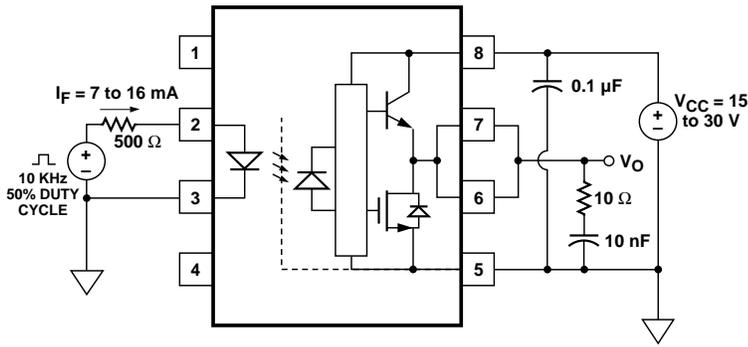


Figure 23. t_{PLH} , t_{PHL} , t_r , and t_f Test Circuit and Waveforms.

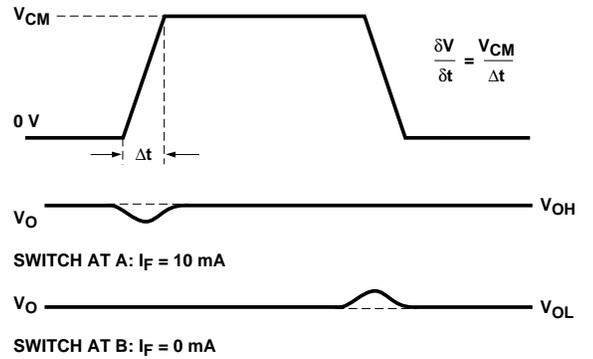
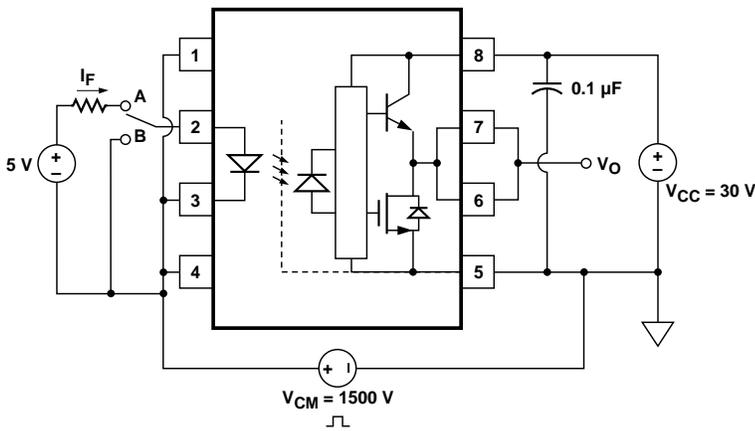


Figure 24. CMR Test Circuit and Waveforms.

Applications Information

Eliminating Negative IGBT Gate Drive (Discussion applies to HCPL-3120, HCPL-J312, and HCNW3120)

To keep the IGBT firmly off, the HCPL-3120 has a very low maximum V_{OL} specification of 0.5 V. The HCPL-3120 realizes this very low V_{OL} by using a DMOS transistor with 1 Ω (typical) on resistance in its pull down circuit. When the HCPL-

3120 is in the low state, the IGBT gate is shorted to the emitter by $R_g + 1 \Omega$. Minimizing R_g and the lead inductance from the HCPL-3120 to the IGBT gate and emitter (possibly by mounting the HCPL-3120 on a small PC board directly above the IGBT) can eliminate the need for negative IGBT gate drive in many applications as shown in Figure 25. Care should be taken with such a PC board design to avoid routing the

IGBT collector or emitter traces close to the HCPL-3120 input as this can result in unwanted coupling of transient signals into the HCPL-3120 and degrade performance. (If the IGBT drain must be routed near the HCPL-3120 input, then the LED should be reverse-biased when in the off state, to prevent the transient signals coupled from the IGBT drain from turning on the HCPL-3120.)

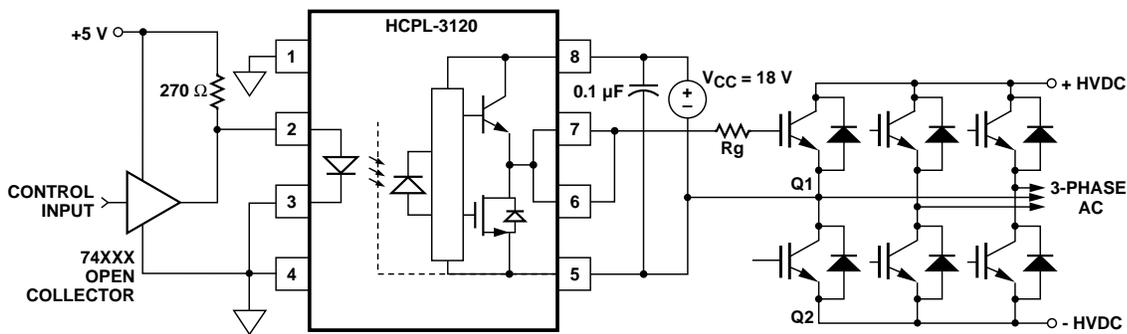


Figure 25. Recommended LED Drive and Application Circuit.

Selecting the Gate Resistor (R_g) to Minimize IGBT Switching Losses. (Discussion applies to HCPL-3120, HCPL-J312 and HCNW3120)

Step 1: Calculate R_g Minimum from the I_{OL} Peak Specification. The IGBT and R_g in Figure 26 can be analyzed as a simple RC circuit with a voltage supplied by the HCPL-3120.

$$\begin{aligned}
 R_g &\geq \frac{(V_{CC} - V_{EE} - V_{OL})}{I_{OLPEAK}} \\
 &= \frac{(V_{CC} - V_{EE} - 2\text{ V})}{I_{OLPEAK}} \\
 &= \frac{(15\text{ V} + 5\text{ V} - 2\text{ V})}{2.5\text{ A}} \\
 &= 7.2\ \Omega \cong 8\ \Omega
 \end{aligned}$$

The V_{OL} value of 2 V in the previous equation is a conservative value of V_{OL} at the peak current of 2.5A (see Figure 6). At lower R_g values the voltage supplied by the HCPL-3120 is not an ideal voltage step. This results in lower peak currents (more margin) than predicted by this analysis. When negative gate drive is not used V_{EE} in the previous equation is equal to zero volts.

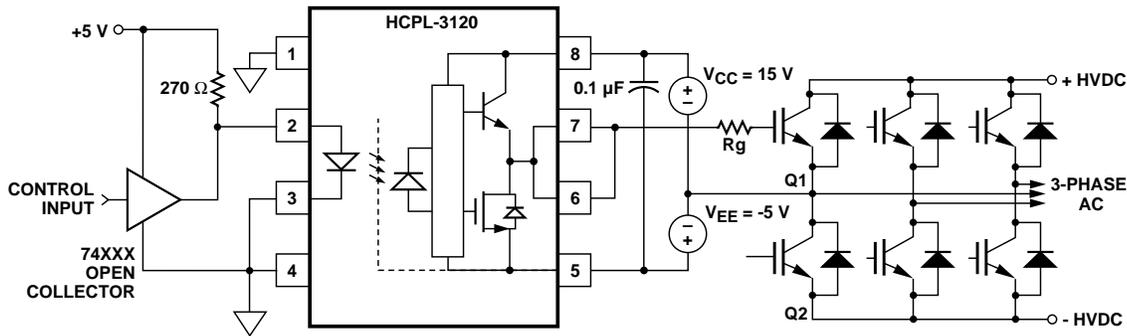


Figure 26. HCPL-3120 Typical Application Circuit with Negative IGBT Gate Drive.

Step 2: Check the HCPL-3120 Power Dissipation and Increase Rg if Necessary. The HCPL-3120 total power dissipation (P_T) is equal to the sum of the emitter power (P_E) and the output power (P_O):

$$P_T = P_E + P_O$$

$$P_E = I_F \cdot V_F \cdot \text{Duty Cycle}$$

$$P_O = P_{O(BIAS)} + P_{O(SWITCHING)}$$

$$= I_{CC} \cdot (V_{CC} - V_{EE}) + E_{SW}(R_G, Q_G) \cdot f$$

For the circuit in Figure 26 with I_F (worst case) = 16 mA, $R_g = 8 \Omega$, Max Duty Cycle = 80%, $Q_g = 500 \text{ nC}$, $f = 20 \text{ kHz}$ and $T_A \text{ max} = 85\text{C}$:

$$P_E = 16 \text{ mA} \cdot 1.8 \text{ V} \cdot 0.8 = 23 \text{ mW}$$

$$P_O = 4.25 \text{ mA} \cdot 20 \text{ V} + 5.2 \mu\text{J} \cdot 20 \text{ kHz}$$

$$= 85 \text{ mW} + 104 \text{ mW}$$

$$= 189 \text{ mW}$$

$$> 178 \text{ mW } (P_{O(MAX)} @ 85\text{C})$$

$$= 250 \text{ mW} - 15\text{C} \cdot 4.8 \text{ mW/C}$$

The value of 4.25 mA for I_{CC} in the previous equation was obtained by derating the $I_{CC} \text{ max}$ of 5 mA (which occurs at -40°C) to $I_{CC} \text{ max}$ at 85C (see Figure 7).

Since P_O for this case is greater than $P_{O(MAX)}$, R_g must be increased to reduce the HCPL-3120 power dissipation.

$$P_{O(SWITCHING MAX)} = P_{O(MAX)} - P_{O(BIAS)}$$

$$= 178 \text{ mW} - 85 \text{ mW}$$

$$= 93 \text{ mW}$$

$$E_{SW(MAX)} = \frac{P_{O(SWITCHING MAX)}}{f}$$

$$= \frac{93 \text{ mW}}{20 \text{ kHz}} = 4.65 \mu\text{W}$$

For $Q_g = 500 \text{ nC}$, from Figure 27, a value of $E_{SW} = 4.65 \mu\text{W}$ gives a $R_g = 10.3 \Omega$.

| P_E Parameter | Description |
|-----------------|------------------------|
| I_F | LED Current |
| V_F | LED On Voltage |
| Duty Cycle | Maximum LED Duty Cycle |

| P_O Parameter | Description |
|--------------------|--|
| I_{CC} | Supply Current |
| V_{CC} | Positive Supply Voltage |
| V_{EE} | Negative Supply Voltage |
| $E_{SW}(R_g, Q_g)$ | Energy Dissipated in the HCPL-3120 for each IGBT Switching Cycle (See Figure 27) |
| f | Switching Frequency |

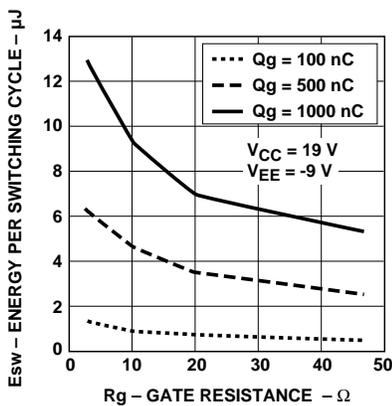


Figure 27. Energy Dissipated in the HCPL-3120 for Each IGBT Switching Cycle.

Thermal Model (Discussion applies to HCPL-3120, HCPL-J312 and HCNW3120)

The steady state thermal model for the HCPL-3120 is shown in Figure 28. The thermal resistance values given in this model can be used to calculate the temperatures at each node for a given operating condition. As shown by the model, all heat generated flows through θ_{CA} which raises the case temperature T_C accordingly. The value of θ_{CA} depends on the conditions of the board design and is, therefore, determined by the designer. The value of $\theta_{CA} = 83^\circ\text{C/W}$ was obtained from thermal measurements using a 2.5 x 2.5 inch PC

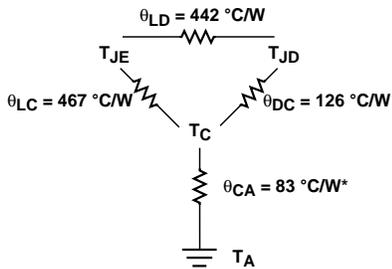


Figure 28. Thermal Model.

board, with small traces (no ground plane), a single HCPL-3120 soldered into the center of the board and still air. The absolute maximum power dissipation derating specifications assume a θ_{CA} value of 83°C/W .

From the thermal mode in Figure 28 the LED and detector IC junction temperatures can be expressed as:

$$T_{JE} = P_E \cdot (\theta_{LC} || (\theta_{LD} + \theta_{DC}) + \theta_{CA}) + \frac{P_D}{T_A} \cdot \left(\frac{\theta_{LC} \cdot \theta_{DC}}{\theta_{LC} + \theta_{DC} + \theta_{LD}} + \theta_{CA} \right)$$

$$T_{JD} = P_E \cdot \left(\frac{\theta_{LC} \cdot \theta_{DC}}{\theta_{LC} + \theta_{DC} + \theta_{LD}} + \theta_{CA} \right) + P_D \cdot (\theta_{DC} || (\theta_{LD} + \theta_{LC}) + \theta_{CA}) + T_A$$

Inserting the values for θ_{LC} and θ_{DC} shown in Figure 28 gives:

$$T_{JE} = P_E \cdot (256^\circ\text{C/W} + \theta_{CA}) + P_D \cdot (57^\circ\text{C/W} + \theta_{CA}) + T_A$$

$$T_{JD} = P_E \cdot (57^\circ\text{C/W} + \theta_{CA}) + P_D \cdot (111^\circ\text{C/W} + \theta_{CA}) + T_A$$

For example, given $P_E = 45 \text{ mW}$, $P_D = 250 \text{ mW}$, $T_A = 70^\circ\text{C}$ and $\theta_{CA} = 83^\circ\text{C/W}$:

$$T_{JE} = P_E \cdot 339^\circ\text{C/W} + P_D \cdot 140^\circ\text{C/W} + T_A$$

$$= 45 \text{ mW} \cdot 339^\circ\text{C/W} + 250 \text{ mW} \cdot 140^\circ\text{C/W} + 70^\circ\text{C} = 120^\circ\text{C}$$

$$T_{JD} = P_E \cdot 140^\circ\text{C/W} + P_D \cdot 194^\circ\text{C/W} + T_A$$

$$= 45 \text{ mW} \cdot 140^\circ\text{C/W} + 250 \text{ mW} \cdot 194^\circ\text{C/W} + 70^\circ\text{C} = 125^\circ\text{C}$$

T_{JE} and T_{JD} should be limited to 125°C based on the board layout and part placement (θ_{CA} specific to the application).

T_{JE} = LED junction temperature
 T_{JD} = detector IC junction temperature
 T_C = case temperature measured at the center of the package bottom
 θ_{LC} = LED-to-case thermal resistance
 θ_{LD} = LED-to-detector thermal resistance
 θ_{DC} = detector-to-case thermal resistance
 θ_{CA} = case-to-ambient thermal resistance
 * θ_{CA} will depend on the board design and the placement of the part.

LED Drive Circuit Considerations for Ultra High CMR Performance.

(Discussion applies to HCPL-3120, HCPL-J312, and HCNW3120)

Without a detector shield, the dominant cause of optocoupler CMR failure is capacitive coupling from the input side of the optocoupler, through the package, to the detector IC as shown in Figure 29. The HCPL-3120 improves CMR performance

by using a detector IC with an optically transparent Faraday shield, which diverts the capacitively coupled current away from the sensitive IC circuitry. However, this shield does not eliminate the capacitive coupling between the LED and optocoupler pins 5-8 as shown in Figure 30. This capacitive coupling causes perturbations in the LED current during common mode transients and becomes the major source of CMR failures for

a shielded optocoupler. The main design objective of a high CMR LED drive circuit becomes keeping the LED in the proper state (on or off) during common mode transients. For example, the recommended application circuit (Figure 25), can achieve 15 kV/ μ s CMR while minimizing component complexity.

Techniques to keep the LED in the proper state are discussed in the next two sections.

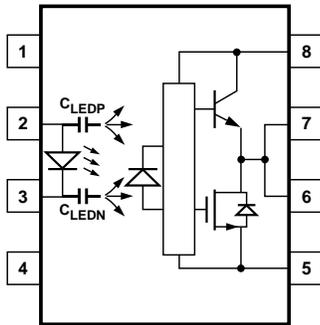


Figure 29. Optocoupler Input to Output Capacitance Model for Unshielded Optocouplers.

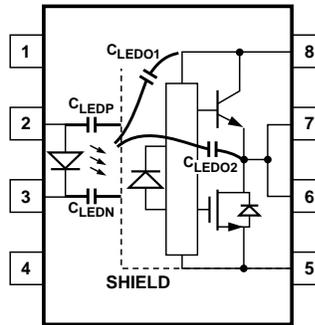


Figure 30. Optocoupler Input to Output Capacitance Model for Shielded Optocouplers.

CMR with the LED On (CMR_H).

A high CMR LED drive circuit must keep the LED on during common mode transients. This is achieved by overdriving the LED current beyond the input threshold so that it is not pulled below the threshold during a transient. A minimum LED current of 10 mA provides adequate margin over the maximum I_{FLH} of 5 mA to achieve $15 \text{ kV}/\mu\text{s}$ CMR.

CMR with the LED Off (CMR_L).

A high CMR LED drive circuit must keep the LED off ($V_F \leq V_{F(OFF)}$) during common mode transients. For example, during a $-dV_{cm}/dt$ transient in Figure 31, the current flowing through C_{LEDP} also flows through the R_{SAT} and V_{SAT} of the logic gate. As long as the low state voltage developed across the logic gate is less than $V_{F(OFF)}$, the LED will remain off and no common mode failure will occur.

The open collector drive circuit, shown in Figure 32, cannot keep the LED off during a $+dV_{cm}/dt$ transient, since all the current flowing through C_{LEDN} must be supplied by the LED, and it is not recommended for applications requiring ultra high CMR_L performance. Figure 33 is an alternative drive circuit which, like the recommended application circuit (Figure 25), does achieve ultra high CMR performance by shunting the LED in the off state.

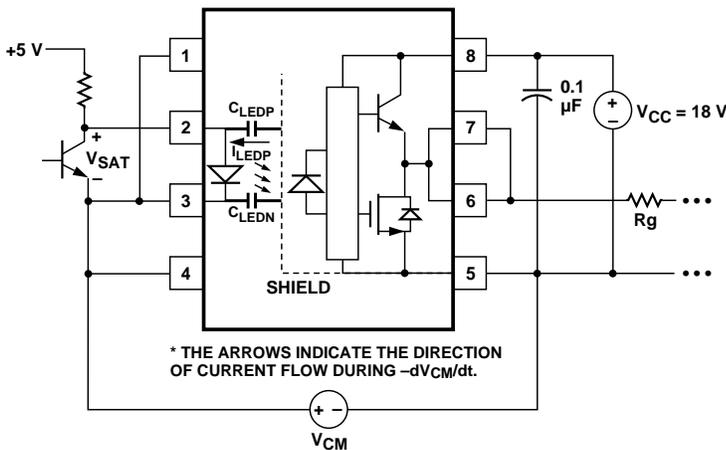


Figure 31. Equivalent Circuit for Figure 25 During Common Mode Transient.

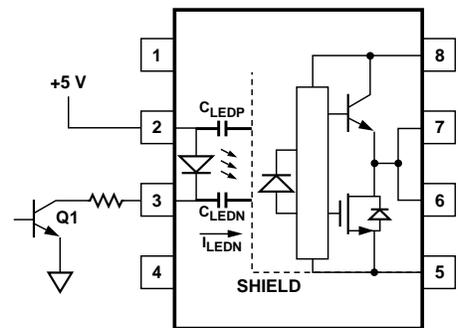


Figure 32. Not Recommended Open Collector Drive Circuit.

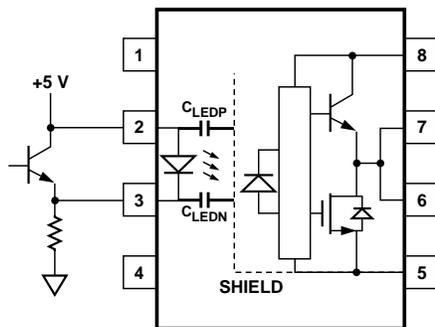


Figure 33. Recommended LED Drive Circuit for Ultra-High CMR.

Under Voltage Lockout Feature. (Discussion applies to HCPL-3120, HCPL-J312, and HCNW3120)

The HCPL-3120 contains an under voltage lockout (UVLO) feature that is designed to protect the IGBT under fault conditions which cause the HCPL-3120 supply voltage (equivalent to the

fully-charged IGBT gate voltage) to drop below a level necessary to keep the IGBT in a low resistance state. When the HCPL-3120 output is in the high state and the supply voltage drops below the HCPL-3120 V_{UVLO-} threshold ($9.5 < V_{UVLO-} < 12.0$) the optocoupler output will go into the low state with a typical delay, UVLO Turn Off Delay, of $0.6 \mu\text{s}$.

When the HCPL-3120 output is in the low state and the supply voltage rises above the HCPL-3120 V_{UVLO+} threshold ($11.0 < V_{UVLO+} < 13.5$) the optocoupler output will go into the high state (assumes LED is "ON") with a typical delay, UVLO Turn On Delay of $0.8 \mu\text{s}$.

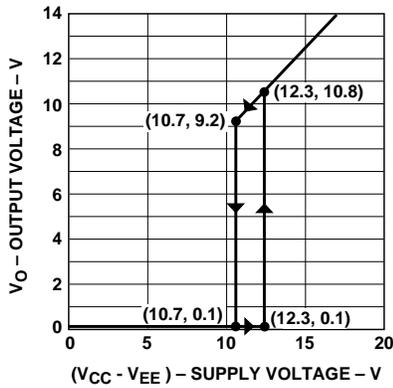


Figure 34. Under Voltage Lock Out.

IPM Dead Time and Propagation Delay Specifications. (Discussion applies to HCPL-3120, HCPL-J312, and HCNW3120)

The HCPL-3120 includes a Propagation Delay Difference (PDD) specification intended to help designers minimize “dead time” in their power inverter

designs. Dead time is the time period during which both the high and low side power transistors (Q1 and Q2 in Figure 25) are off. Any overlap in Q1 and Q2 conduction will result in large currents flowing through the power devices between the high and low voltage motor rails.

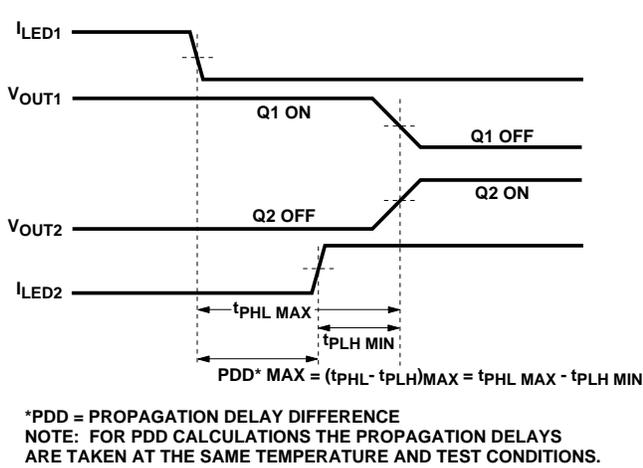


Figure 35. Minimum LED Skew for Zero Dead Time.

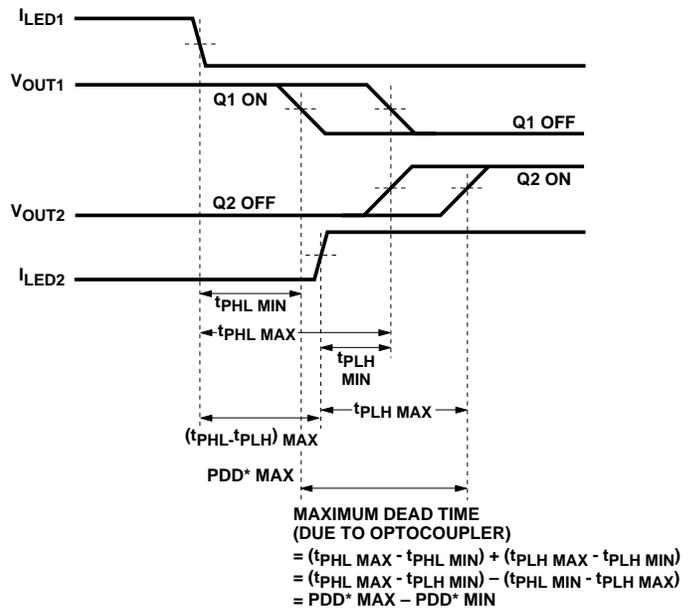


Figure 36. Waveforms for Dead Time.

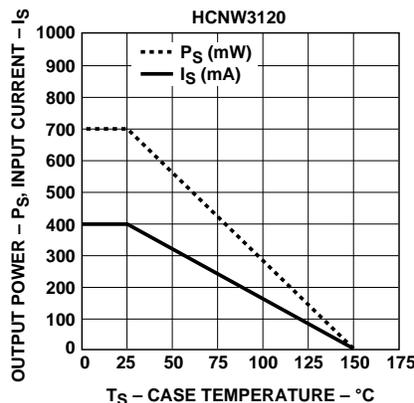
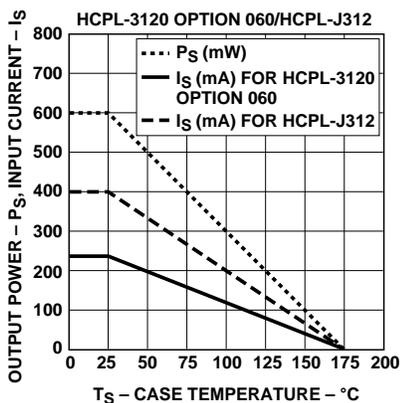
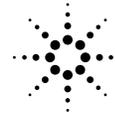


Figure 37. Thermal Derating Curve, Dependence of Safety Limiting Value with Case Temperature per VDE 0884.



To minimize dead time in a given design, the turn on of LED2 should be delayed (relative to the turn off of LED1) so that under worst-case conditions, transistor Q1 has just turned off when transistor Q2 turns on, as shown in Figure 35. The amount of delay necessary to achieve this conditions is equal to the maximum value of the propagation delay difference specification, PDD_{MAX} , which is specified to be 350 ns over the operating temperature range of -40°C to 100°C.

Delaying the LED signal by the maximum propagation delay difference ensures that the minimum dead time is zero, but it does not tell a designer what the maximum dead time will be. The maximum dead time is equivalent to the difference between the maximum and minimum propagation delay difference specifications as shown in Figure 36. The maximum dead time for the HCPL-3120 is 700 ns (= 350 ns - (-350 ns)) over an operating temperature range of -40°C to 100°C.

Note that the propagation delays used to calculate PDD and dead time are taken at equal temperatures and test conditions since the optocouplers under consideration are typically mounted in close proximity to each other and are switching identical IGBTs.